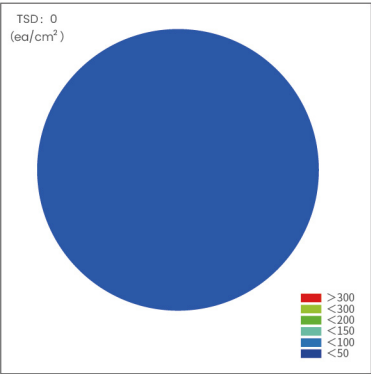


Basic product information

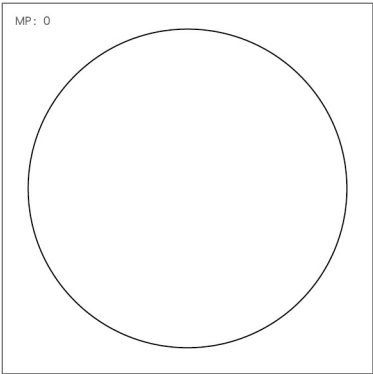


N-type Silicon Carbide Substrate (4 inch / 6 inch / 8 inch)

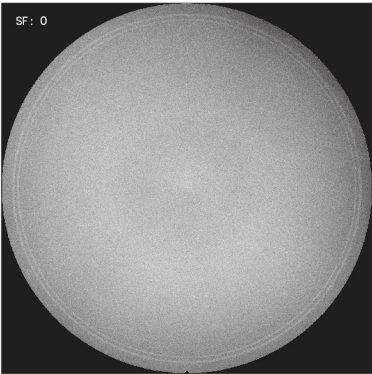
Grade	Production Grade	Dummy Grade
Diameter	100.0 mm±0.25 mm/150.0 mm±0.25 mm/200.0 ± 0.25 mm	
Thickness	350.0 μm ±25.0 μm/500.0 μm ±25.0 μm	
Dopant	Nitrogen	
Micropipe Density	≤ 0.1 /cm ²	≤ 5 /cm ²
Surface Finish	Double side polish, Si epi-face CMP, C face optical polish	



TSD 0 cm⁻²



MP 0



SF 0

*For more detailed information regarding our products,
please do not hesitate to contact us for consultation and discussion.